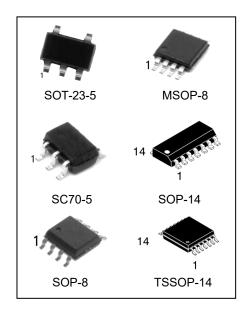


1MHz, 45µA, CMOS, Rail-to-Rail OPERATIONAL AMPLIFIERS

FEATURES

- LOW IQ: 45µA typical
- LOW COST
- RAIL-TO-RAIL INPUT AND OUTPUT
- SINGLE SUPPLY: +2.1V to +5.5V
- INPUT BIAS CURRENT: 0.5pA
- HIGH SPEED: POWER WITH BANDWIDTH: 1MHz
- SMALL PACKAGE: OPA348 Available in SOT23-5 SC70-5 and SOP-8 Packages OPA2348 Available in MSOP-8 and SOP-8 Packages OPA4348 Available in SOP-14 and TSSOP-14 Packages



ORDERING INFORMATION

DEVICE	Package Type	MARKING	Packing	Packing Qty
OPA348M5/TR	SOT-23-5	A348	REEL	3000pcs/reel
OPA348M7/TR	SC70-5	A348	REEL	3000pcs/reel
OPA348M/TR	SOP-8	OPA348	REEL	2500pcs/reel
OPA2348M/TR	SOP-8	OPA2348,A2348	REEL	2500pcs/reel
OPA2348MM/TR	MSOP-8	A2348	REEL	3000pcs/reel
OPA4348M/TR	SOP-14	OPA4348	REEL	2500pcs/reel
OPA4348MT/TR	TSSOP-14	OPA4348,A4348	REEL	2500pcs/reel



DESCRIPTION

The OPA348 series amplifiers are single supply, low-power, CMOS opamps in micro packaging. Featuring an extended bandwidth of 1MHz, and a supply current of 45µA, the OPA348 series is useful for low-power applications on single supplies of 2.1V to 5.5V.

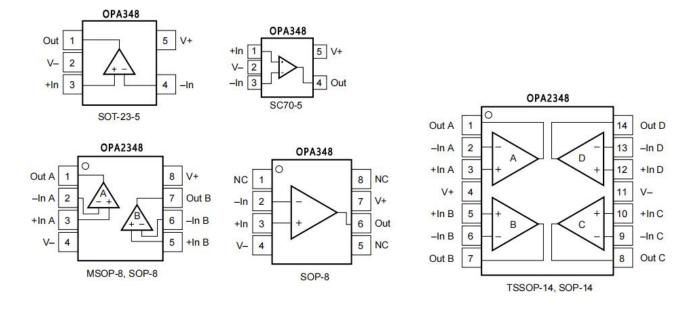
Low supply current of 45µA, and an input bias current of 0.5pA, make the OPA348 series an optimal candidate for low-power, high-impedance applications such as smoke de- tectors and other sensors.

The OPA348 is available in the miniature SC70-5, SOT23-5 and SOP-8 packages. The OPA2348 is available in MSOP-8 and SOP-8 packages, and the OPA4348 is offered in space-saving TSSOP-14 and SOP-14 packages. The ex- tended temperature range of -40°C to +125°C over all supply voltages offers additional design flexibility.

APPLICATIONS

- PORTABLE EQUIPMENT
- BATTERY-POWERED EQUIPMENT
- SMOKE ALARMS
- CO DETECTORS
- MEDICAL INSTRUMENTATION

PIN ASSIGNMENT





ABSOLUTE MAXIMUM RATINGS⁽¹⁾

CONDITION	MIN	MAX	UNITS
Supply Voltage		7.5	V
Signal Input Terminals Voltage ⁽²⁾	(V-)-0.5	(V+)+0.5	V
Signal Input Terminals Current ⁽²⁾	10	mA	
Output Short-Circuit ⁽³⁾	Contir		
Operating Temperature	-40	+125	°C
Storage Temperature	-65 +150		°C
Junction Temperature	15	°C	
Lead Temperature (soldering, 10s)	24	°C	

NOTES:

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only. Functional opera- tion of the device at these conditions, or beyond the specified operating conditions, is not implied. (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current-limited to 10mA or less. (3) Short-circuit to ground, one amplifier per package.

ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. HGSEMI recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degrada- tion to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



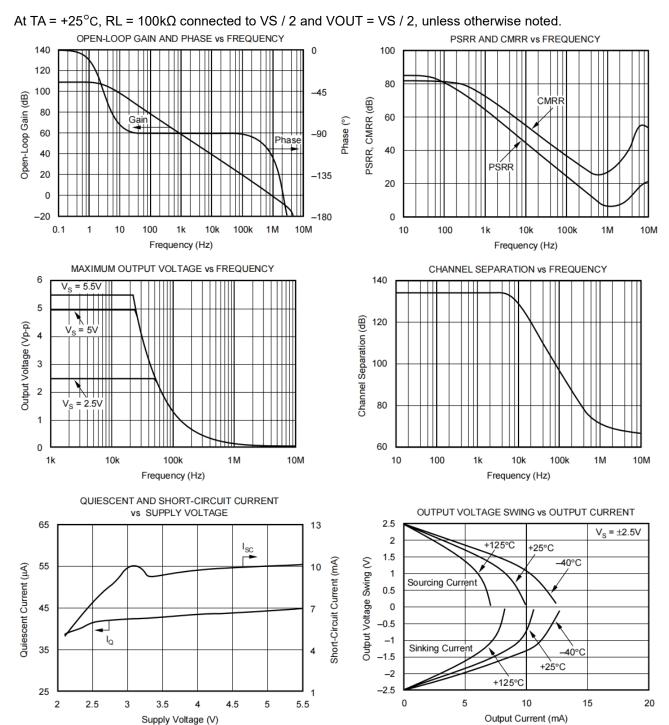
ELECTRICAL CHARACTERISTICS: $V_s = 2.5V$ to 5.5V

Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $+125^{\circ}C$ At $T_A = +25^{\circ}C$, $R_L = 100k\Omega$ connected to $V_S/2$ and $VOUT = V_S/2$, unless otherwise noted.

PARAMETER	CONDITION	OPA3	OPA348/OPA2348/OPA4348				
		MIN	TYP	MAX	UNITS		
OFFSET VOLTAGE	VS = 5V, VCM = (V–) + 0.8V		1	5	mV		
Input Offset Voltage V _{os}			-	6	mV		
Over Temperature			4		µ/C		
DriftdVOS/dT	VS = 2.5V to 5.5V, VCM < (V+) – 1.7V		60	175	μ/V		
vs Power SupplyPSRR	$V_{S} = 2.5V$ to 5.5V, $V_{CM} < (V_{+}) - 1.7V$ $V_{S} = 2.5V$ to 5.5V, $V_{CM} < (V_{+}) - 1.7V$			300	μ/V		
Over Temperature	VS = 2.3V to 3.3V, VCIVI < (VI) = 1.7V		0.2	300	μ/V		
Channel Separation, dcf = 1kHz			134		dB		
INPUT VOLTAGE RANGE							
Common-Mode Voltage Range V _{CM}		(V–) – 0.2		(V+) + 0.2	V		
Common-Mode Rejection Ratio CMRR	(V-)-0.2V <vcm<(v+)-1.7v< td=""><td>70</td><td>82</td><td></td><td>dB</td></vcm<(v+)-1.7v<>	70	82		dB		
over Temperature	(V-)-0.2V <vcm<(v+)-1.7v< td=""><td>66</td><td></td><td></td><td>dB</td></vcm<(v+)-1.7v<>	66			dB		
•	VS=5.5V,(V-)-0.2 <vcm<(v+)+0.2v< td=""><td>60</td><td>71</td><td></td><td>dB</td></vcm<(v+)+0.2v<>	60	71		dB		
over Temperature	VS=5.5V,(V-) <vcm<(v+)< td=""><td>56</td><td></td><td></td><td>dB</td></vcm<(v+)<>	56			dB		
INPUT BIAS CURRENT							
			0.5	10			
Input Bias Current I _B			0.5	10	pApA		
		-	0.5 10 ¹³ 3	10			
INPUT IMPEDANCE			10 ¹³ 3 10 ¹³ 6		Ω∥ pF		
Differential Common-Mode			0101010		Ω∥ pF		
NOISE	VCM < (V+) – 1.7V		10		Vр <u>-р</u>		
Input Voltage Noise, f = 0.1Hz to 10Hz	,		-	-			
Input Voltage Noise Density, f = 1kHz e _n			35		nV/Hz		
Input Current Noise Density, f = 1kHz in			4		fA/Hz		
OPEN-LOOP GAIN							
Open-Loop Voltage Gain A _{OL}	Vs=5V,RL=100KΩ,0.025V <vo<4.975v< td=""><td>94</td><td>108</td><td></td><td>dB</td></vo<4.975v<>	94	108		dB		
over Temperature	Vs=5V,RL=100KΩ,0.025V <vo<4.975v< td=""><td>90</td><td></td><td></td><td>dB</td></vo<4.975v<>	90			dB		
	Vs=5V,RL=5KΩ,0.125V <vo<4.875v< td=""><td>90</td><td>98</td><td></td><td>dB</td></vo<4.875v<>	90	98		dB		
over Temperature	Vs=5V,RL=5KΩ,0.125V <vo<4.875v< td=""><td>88</td><td></td><td></td><td>dB</td></vo<4.875v<>	88			dB		
OUTPUT				· · · · · ·			
Voltage Output Swing from Rail	RL = 100kΩ, AOL > 94dB		18	25	mV		
		-	10				
over Temperature	$R_{L} = 100k\Omega, AO_{L} > 90dB$		100	25	mV mV		
T	$R_{L} = 5k\Omega, A_{OL} > 90dB$		100	125	mV		
over Temperature	$RL = 5k\Omega, AOL > 88dB$			125	mV		
Short-Circuit Current I _{SC}			10		mA		
Capacitive Load Drive C _L OAD		See Ty	pical Characte	ristics			
FREQUENCY RESPONSE	CL = 100pE		4		N 41 1-		
Gain-Bandwidth Product GBW	CL = 100pF		1		MHz		
Slew Rate SR	G = +1		0.5		V/s		
Settling Time, 0.1% t _s	VS = 5.5V, 2V Step, G = +1		5		μs		
0.01%	VS = 5.5V, 2V Step, G = +1		7		μs		
Overload Recovery Time	$V_{IN} \cdot Gain > V_S$		1.6		μs		
· · · · · · · · · · · · · · · · · · ·	Vs = 5.5V, Vo = 3Vp-p, G = +1, f = 1kH:	z	0.0023		<u>%</u>		
POWER SUPPLY							
Specified Voltage Range V _S		2.5		5.5	V		
Minimum Operating Voltage		2.0	2.1 to 5.5	0.0	V		
Quiescent Current (per amplifier) I _Q			2.1 10 0.0	65			
over Temperature	I ₀ = 0		45	65 75	μA		
•				13	μΑ		
					-		
Specified Range		-40		125	°C		
Operating Range		-65		150	°C		
Storage Range		-65		150	°C		
Thermal Resistance JA							
SOT23-5 Surface-Mount			200		°C/W		
SOT23-8 Surface-Mount			150		∘C/W		
MSOP-8 Surface-Mount			150		°C/W		
SO-8 Surface-Mount			150		∘C/W		
SO-14 Surface-Mount			100		•C/W		
TSSOP-14 Surface-Mount		1	100	<u> </u>	•C/W		
	1		100		0,00		



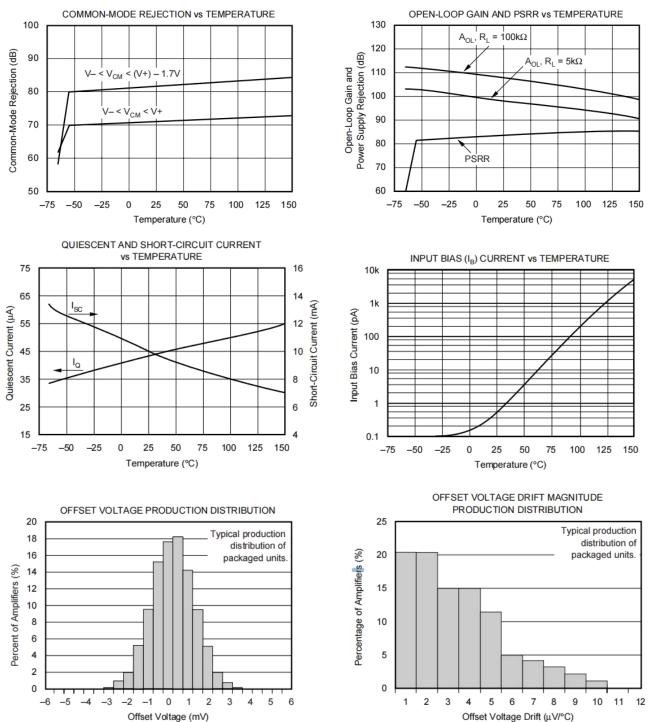
TYPICAL CHARACTERISTICS





TYPICAL CHARACTERISTICS (Cont.)

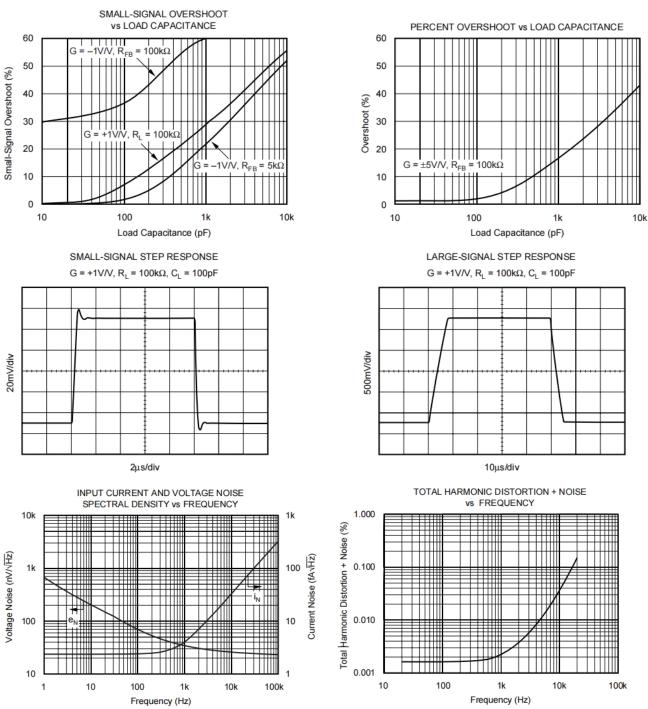
At TA = +25°C, RL = $100k\Omega$ connected to VS / 2 and VOUT = VS / 2, unless otherwise noted.





TYPICAL CHARACTERISTICS (Cont.)

At TA = +25°C, RL = $100k\Omega$ connected to VS / 2 and VOUT = VS / 2, unless otherwise noted





APPLICATIONS INFORMATION

OPA348 series op amps are unity-gain stable and suitable for a wide range of general-purpose applications.

The OPA348 series features wide bandwidth and unity-gain stability with rail-to-rail input and output for increased dynamic range. Figure 1 shows the input and output waveforms for the OPA348 in unity-gain configuration. Operation is from a single+5V supply with a 100k Ω load connected to VS/2. The input isa 5Vp-p sinusoid. Output voltage is approximately 4.98Vp-p.Power-supply pins should be bypassed with 0.01µF ceramic capacitors.

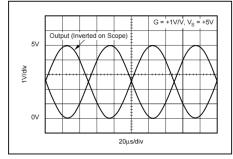


FIGURE 1. The OPA348 Features Rail-to-Rail Input/Output.

OPERATING VOLTAGE

OPA348 series op amps are fully specified and tested from +2.5V to +5.5V. However, supply voltage may range from +2.1V to +5.5V. Parameters are tested over the specified supply range—a unique feature of the OPA348 series. In addition, all temperature specifications apply from –40°C to +125°C. Most behavior remains virtually unchanged through out the full operating voltage range. Parameters that vary significantly with operating voltages or temperature are shown in the Typical Characteristics.

COMMON-MODE VOLTAGE RANGE

The input common-mode voltage range of the OPA348 series extends 200mV beyond the supply rails. This is achieved with a complementary input stage—an N-channel input differ ential pair in parallel with a P-channel differential pair. The N-channel pair is active for input voltages close to the positive rail, typically (V+) - 1.2V to 300mV above the positive supply, while the P-channel pair is on for inputs from 300mV below the negative supply to approximately (V+) - 1.4V. There is a small transition region, typically (V+) - 1.4V to (V+) - 1.2V, in which both pairs are on. This 200mV transition region, shown in Figure 2, can vary ±300mV with process variation. Thus, the transition region (both stages on) can range from (V+) - 1.7V to (V+) - 1.5V on the low end, up to (V+) - 1.1V to (V+) - 0.9Von the high end. Within the 200mV transition region PSRR, CMRR, offset voltage, offset drift, and THD may be degraded compared to operation outside this region.

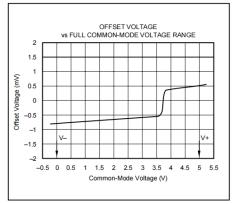


FIGURE 2. Behavior of Typical Transition Region at Room Temperature.



RAIL-TO-RAIL INPUT

The input common-mode range extends from (V-) - 0.2V to (V+) + 0.2V. For normal operation, inputs should be limited to this range. The absolute maximum input voltage is 500mV beyond the supplies. Inputs greater than the input common-mode range but less than the maximum input voltage, while not valid, will not cause any damage to the op amp. Unlike some other op amps, if input current is limited the inputs may go beyond the power supplies without phase inversion, as shown in Figure 3.

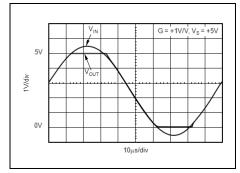
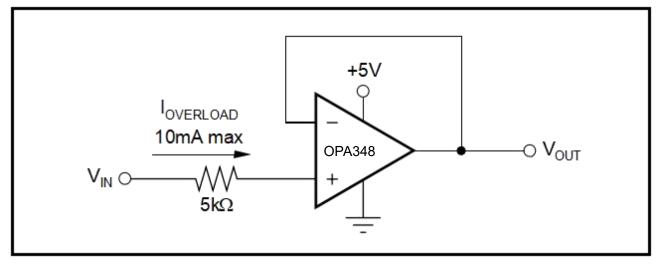


FIGURE 3. OPA348—No Phase Inversion with Inputs Greater than the Power-Supply Voltage.

Normally, input currents are 0.5pA. However, large inputs (greater than 500mV beyond the supply rails) can cause excessive current to flow in or out of the input pins. There- fore, as well as keeping the input voltage below the maxi- mum rating, it is also important to limit the input current to less than 10mA. This is easily accomplished with an input voltage resistor, as shown in Figure 4.





RAIL-TO-RAIL OUTPUT

A class AB output stage with common-source transistors is used to achieve rail-to-rail output. This output stage is ca- pable of driving $5k\Omega$ loads connected to any potential be- tween V+ and ground. For light resistive loads (> $100k\Omega$), the output voltage can typically swing to within 18mV from supply rail. With moderate resistive loads ($10k\Omega$ to $50k\Omega$), the output voltage can typically swing to within 100mV of the supply rails while maintaining high open-loop gain (see the typical characteristic "Output Voltage Swing vs Output Current").



CAPACITIVE LOAD AND STABILITY

The OPA348 in a unity-gain configuration can directly drive up to 250pF pure capacitive load. Increasing the gain enhances the amplifier's ability to drive greater capacitive loads (see the typical characteristic "Small-Signal Overshoot vs Capacitive Load"). In unity-gain configurations, capacitive load drive can be improved by inserting a small (10Ω to 20Ω) resistor, RS, in series with the output, as shown in Figure 5. This significantly reduces ringing while maintaining DC performance for purely capacitive loads. However, if there is a resistive load in parallel with the capacitive load, a voltage divider is created, introducing a Direct Current (DC) error at the output and slightly reducing the output swing. The error introduced is proportional to the ratio RS/RL, and is generally negligible.

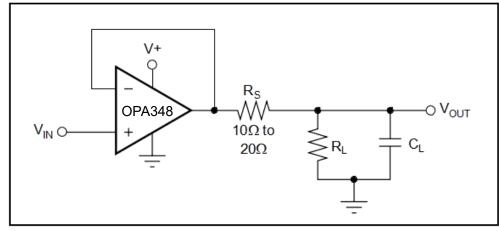


FIGURE 5. Series Resistor in Unity-Gain Buffer Configura- tion Improves Capacitive Load Drive.

In unity-gain inverter configuration, phase margin can be reduced by the reaction between the capacitance at the op amp input, and the gain setting resistors, thus degrading capacitive load drive. Best performance is achieved by using small valued resistors. For example, when driving a 500pF load, reducing the resistor values from 100k Ω to 5k Ω de- creases overshoot from 55% to 13% (see the typical charac- teristic "Small-Signal Overshoot vs. Load Capacitance"). However, when large valued resistors cannot be avoided, a small (4pF to 6pF) capacitor, CFB, can be inserted in the feedback, as shown in Figure 6. This significantly reduces overshoot by compensating the effect of capacitance, CIN, which includes the amplifier's input capacitance and PC board parasitic capacitance.

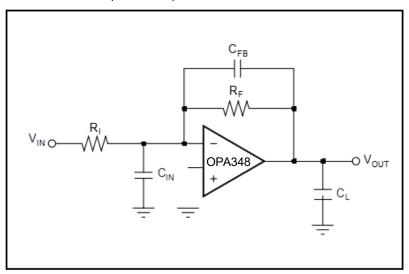


FIGURE 6. Improving Capacitive Load Drive.



DRIVING A/D CONVERTERS

The OPA348 series op amps are optimized for driving medium-speed sampling Analog-to-Digital Converters (ADCs). The OPA348 op amps buffer the ADCs input capacitance and resulting charge injection while providing signal gain.

The OPA348 in a basic noninverting configuration driving the ADS7822, see Figure 7. The ADS7822 is a 12-bit, microPOWER sampling converter in the MSOP-8 package. When used with the low-power, miniature packages of the OPA348, the combination is ideal for space-limited, low- power applications. In this configuration, an RC network at the ADC's input can be used to provide for anti-aliasing filter and charge injection current.

The OPA348 in noninverting configuration driving ADS7822 limited, low-power applications. In this configuration, an RC network at the ADC's input can be used to provide for anti- aliasing filter and charge injection current. See Figure 8 for the OPA2348 driving an ADS7822 in a speech bandpass filtered data acquisition system. This small, low-cost solution provides the necessary amplification and signal conditioning to interface directly with an electret microphone. This circuit will operate with VS = 2.7V to 5V with less than 250μ A typical quiescent current.



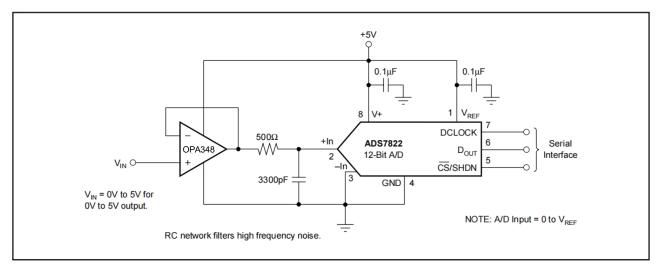
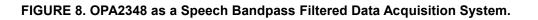
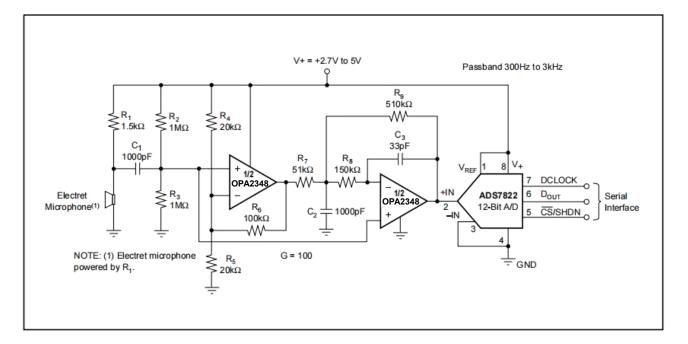


FIGURE 7. OPA348 in Noninverting Configuration Driving ADS7822.

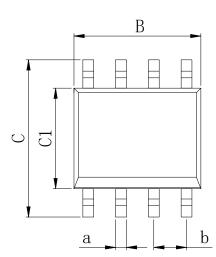


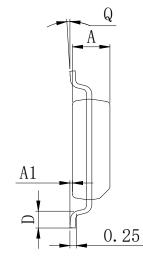




PHYSICAL DIMENSIONS

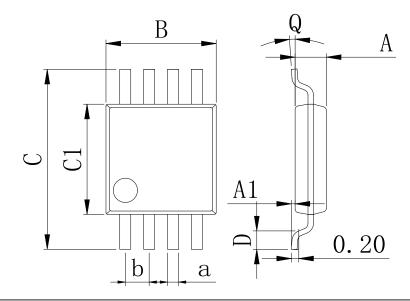
SOP-8





Dimensions In Millimeters(SOP-8)										
Symbol:	А	A1	В	С	C1	D	Q	а	b	
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1 07 860	
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	1.27 BSC	

MSOP-8

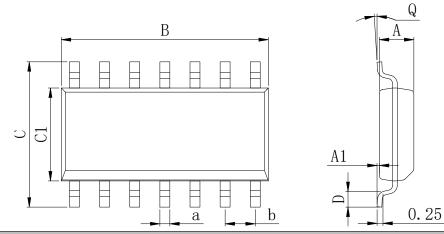


Dimensions In Millimeters(MSOP-8)										
Symbol:	A	A1	В	С	C1	D	Q	а	b	
Min:	0.80	0.05	2.90	4.75	2.90	0.35	0°	0.25	0.65 BSC	
Max:	0.90	0.20	3.10	5.05	3.10	0.75	8°	0.35	0.05 830	



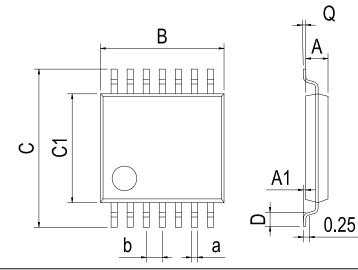
PHYSICAL DIMENSIONS

SOP-14



Dimensions In Millimeters(SOP-14)										
Symbol:	A	A1	В	С	C1	D	Q	а	b	
Min:	1.35	0.05	8.55	5.80	3.80	0.40	0°	0.35	1.27 BSC	
Max:	1.55	0.20	8.75	6.20	4.00	0.80	8°	0.45	1.27 630	

TSSOP-14

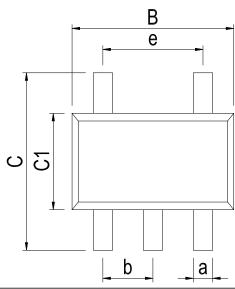


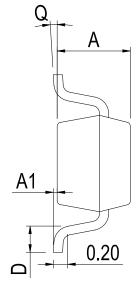
Dimensions In Millimeters(TSSOP-14)										
Symbol:	А	A1	В	С	C1	D	Q	а	b	
Min:	0.85	0.05	4.90	6.20	4.30	0.40	0°	0.20	0.65 BSC	
Max:	0.95	0.20	5.10	6.60	4.50	0.80	8°	0.25	0.05 BSC	



PHYSICAL DIMENSIONS

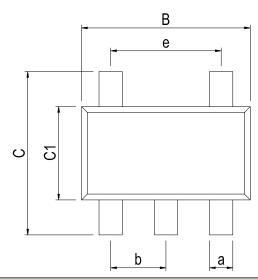
SOT-23-5

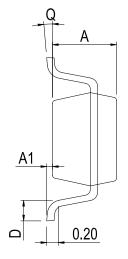




Dimensions In Millimeters(SOT-23-5)										
Symbol:	A	A1	В	С	C1	D	Q	а	b	е
Min:	1.05	0.00	2.82	2.65	1.50	0.30	0°	0.30	0.05 000	1.90 BSC
Max:	1.15	0.15	3.02	2.95	1.70	0.60	8°	0.40	0.95 BSC	

SC70-5



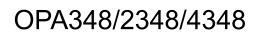


Dimensions In Millimeters(SC70-5)											
Symbol:	A	A1	В	С	C1	D	Q	а	b	е	
Min:	0.90	0.00	2.00	2.15	1.15	0.26	0°	0.15	0.65	1.30 BSC	
Max:	1.00	0.15	2.20	2.45	1.35	0.46	8°	0.35	BSC	1.30 BSC	



REVISION HISTORY

DATE	REVISION	PAGE
2019-12-15	New	1-17
2023-10-31	Update Lead Temperature、Update encapsulation type、Update SC70-5 Physical Dimensions	3、1、15





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